

HEXFET® POWER MOSFET PHOTOVOLTAIC RELAY

PVO402P

Microelectronic

Power IC Relay

Single Pole, Normally Open + Ring Detector

0-400V, 120mA AC/DC

General Description

The PVO402P Photovoltaic Relay is a single-pole, normally open solid-state relay plus ring detector. By integrating these two functions in one package it can replace two discrete components, i.e., a relay and an AC-input opto-coupler. The relay portion of PVO402P utilizes International Rectifier's HEXFET power MOSFET as the output switch, driven by an integrated circuit photovoltaic generator of novel construction. The output switch is controlled by radiation from a GaAlAs light emitting diode (LED) which is optically isolated from the photovoltaic generator. The ring detector portion of PVO402P has two LEDs in inverse parallel connection as the input sensing element and a silicon NPN photo-transistor as the output switch.

PVO402P is ideally suited for PCMCIA fax/modem cards. Its extremely low profile allows it to be used in Type II cards whose outer shells are only 5mm thick.

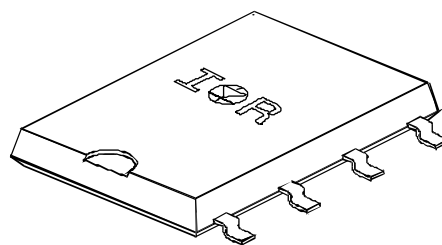
PVO402P Relays are packaged in an 8-pin, molded 'Thin-Pak' DIP package with 'gull-wing' surface mount terminals. It is available in plastic shipping tubes or on tape-and-reel. Please refer to Part Identification (opposite) for details.

Applications

- On/Off Hook switch ■
- Dial pulsing ■
- Ringer injection ■
- Ring detection ■
- Loop current detection ■

PVO402P Features

- HEXFET Power MOSFET output ■
- Bounce-free operation ■
- 3,750 V_{RMS} I/O isolation ■
- Linear AC/DC operation ■
- Solid-State reliability ■
- UL recognized ■



PVO402P
'Thin-Pak'

Part Identification

PVO402P	SMT, plastic shipping tube
PVO402P-T	SMT, T&R

(HEXFET is the registered trademark for International Rectifier Power MOSFETs)

Electrical Specifications ($-40^{\circ}\text{C} \leq T_A \leq +85^{\circ}\text{C}$ unless otherwise specified)**RELAY**

INPUT CHARACTERISTICS	Limits	Units
Min. Control Current (See Fig.1)	3.0	mA
Max. Control Current for Off-State Resistance @ $T_A = +25^{\circ}\text{C}$	0.4	mA
Control Current Range (Caution: current limit input LED, see Fig.6)	3.0 to 25	mA
Max. Reverse Voltage	7.0	V

OUTPUT CHARACTERISTICS	Limits	Units
Operating Voltage Range	0 to ± 400	$V_{(DC \text{ or } AC \text{ peak})}$
Max. Load Current @ $T_A = +40^{\circ}\text{C}$ 5mA Control (See Fig.1)	120	mA
Max. On-State Resistance @ $T_A = +25^{\circ}\text{C}$ For 50mA Pulsed Load, 5mA Control (See Fig.4)	35	Ω
Max. Off-State Leakage @ $T_A = +25^{\circ}\text{C}$, $\pm 400\text{V}$ (See Fig.5)	1.0	μA
Max. Turn-On Time @ $T_A = +25^{\circ}\text{C}$ (See Fig. 7) For 50mA, 100 V_{DC} Load, 5mA Control	2.0	ms
Max. Turn-Off Time @ $T_A = +25^{\circ}\text{C}$ (See Fig. 7) For 50mA, 100 V_{DC} Load, 5mA Control	0.5	ms
Max. Output Capacitance @ 50 V_{DC}	12	pF

DETECTOR

INPUT CHARACTERISTICS	Limits	Units
Min. Control Current @ $I_C = 2\text{mA}$, $V_{CE} = 0.5\text{V}$	6.0	mA
Max. Control Current for Off-State Leakage $I_C = 1\mu\text{A}$, $V_{CE} = 5\text{V}$ @ $T_A = +25^{\circ}\text{C}$	5	μA
Control Current Range (Caution: current limit input LED, see Fig.6)	6.0 to 25	mA

OUTPUT CHARACTERISTICS	Limits	Units
Min. Collector-Emitter Breakdown Voltage @ $I_C = 10\mu\text{A}$	20	V_{DC}
Min. Current Transfer Ratio @ $I_{LED} = 6\text{mA}$, $V_{CE} = 5\text{V}$ (see Fig. 9)	33	%
Max. Saturation Voltage @ $I_{LED} = 16\text{mA}$, $I_C = 2\text{mA}$	0.5	V
Max. Leakage Current @ $I_{LED} = 0\text{mA}$, $V_{CE} = 5\text{V}$	500	nA
Max. Power Dissipation @ $T_A = +25^{\circ}\text{C}$ (derate linearly 2.0mW/ $^{\circ}\text{C}$)	150	mW

COMBINED

GENERAL CHARACTERISTICS	Limits	Units
Min. Dielectric Strength, Input-Output	3750	V_{RMS}
Min. Dielectric Strength, Relay-Detector	1000	V_{DC}
Min. Insulation Resistance, Input-Output @ $T_A = +25^{\circ}\text{C}$, 50%RH, 100 V_{DC}	10^{12}	Ω
Max. Capacitance, Input-Output	3.0	pF
Max. Pin Soldering Temperature (10 seconds max.)	+260	$^{\circ}\text{C}$
Ambient Temperature Range: Operating Storage	-40 to +85 -40 to +100	

Connection Diagram

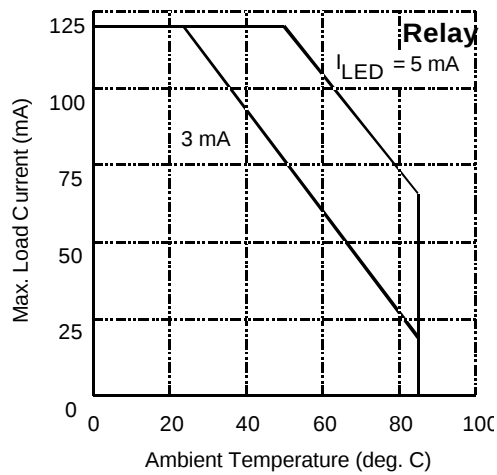
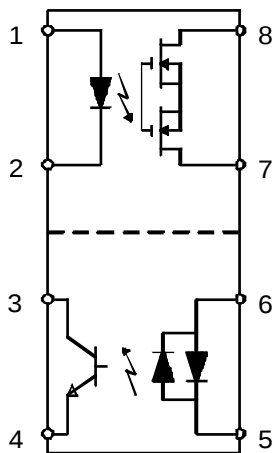


Figure 1. Current Derating Curve

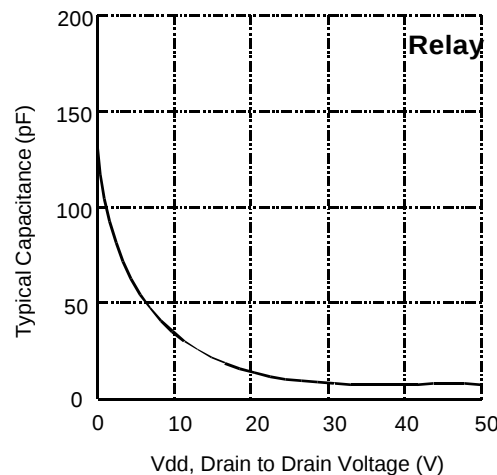


Figure 2. Typical Output Capacitance

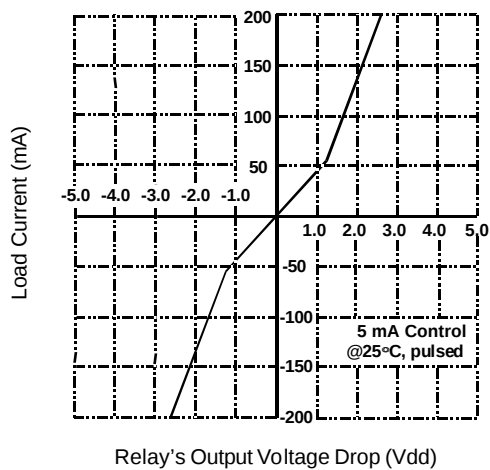


Figure 3. Linearity Characteristics

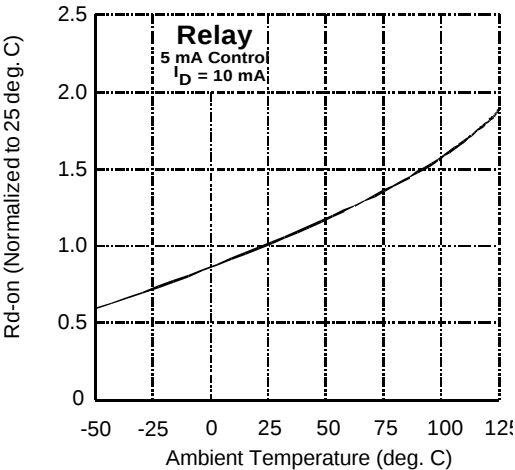


Figure 4. Typical Normalized On-Resistance

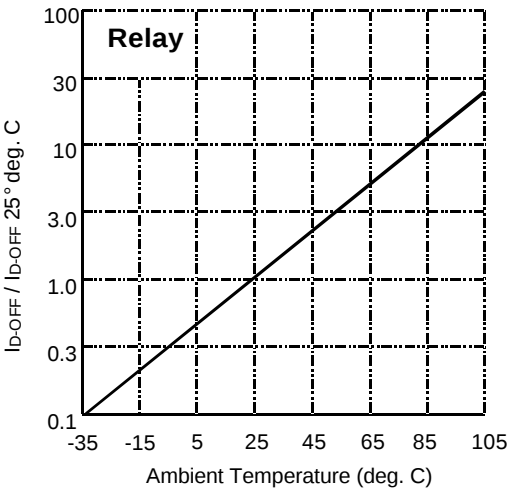


Figure 5. Typical Normalized Off-State Leakage

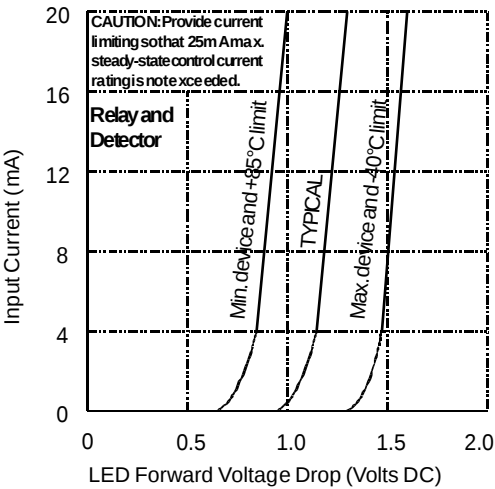


Figure 6. Input Characteristics (Current Controlled)

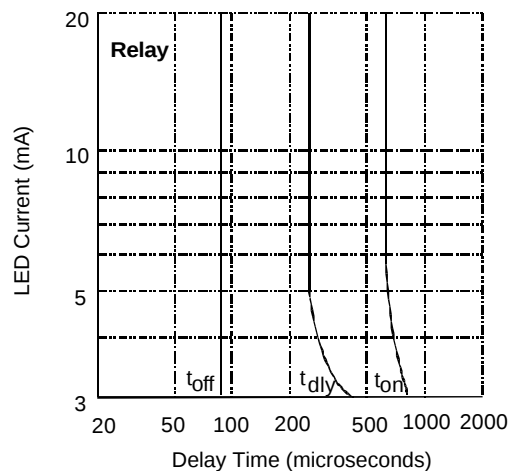


Figure 7. Typical Delay Times

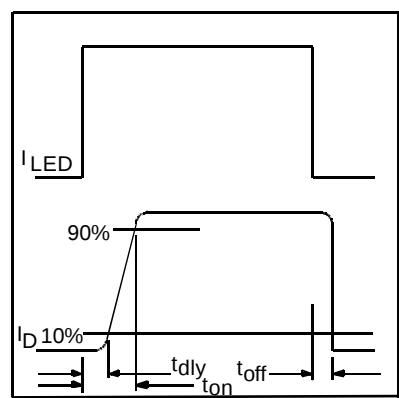


Figure 8. Delay Time Definitions

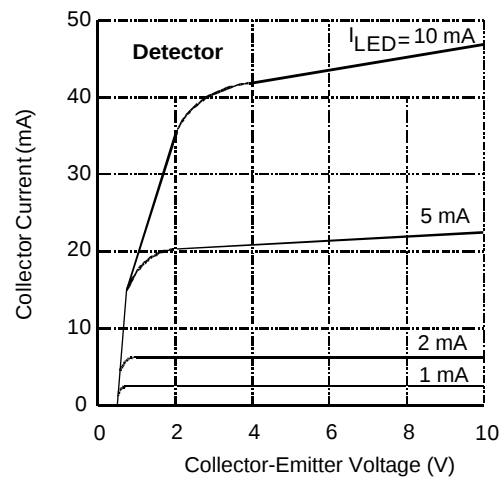
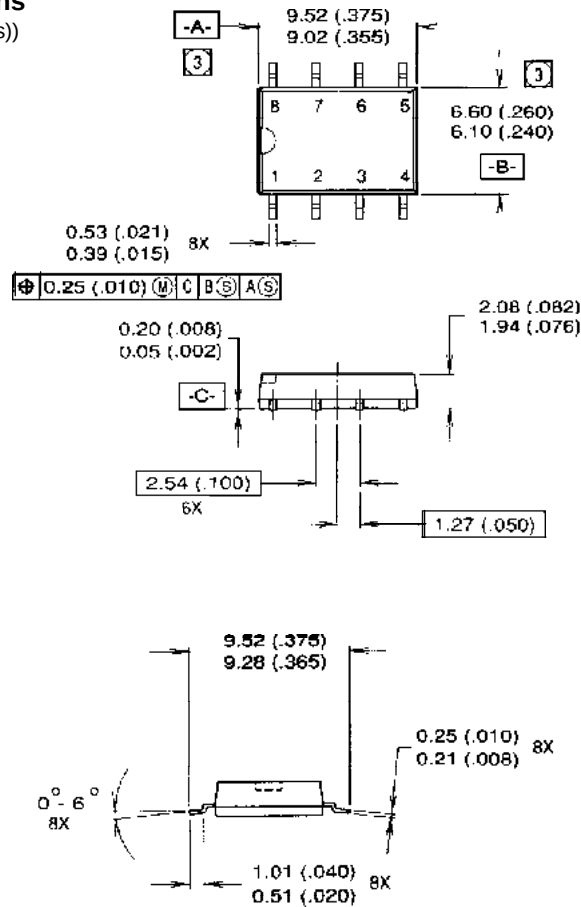


Figure 9. Typical Transfer Characteristics

Mechanical Specifications

(Dimensions in millimeters (inches))



1. CONTROLLING DIMENSION: INCH

③ DIMENSION DOES NOT INCLUDE MOLD PROTRUSIONS. MOLD PROTRUSIONS SHALL NOT EXCEED 0.25 (.010).

International
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Data and specifications subject to change without notice. 8/97